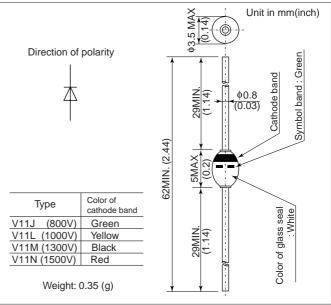


FEATURES

- For high speed switching.
- Diffused-junction. Glass passivated and encapsulated.

OUTLINE DRAWING



ABSOLUTE MAXIMUM RATINGS

Items	Туре		V11J	V11L	V11M	V11N			
Repetitive Peak Reverse Voltage	V _{RRM}	V	800	1000	1300	1500			
Non-Repetitive Peak Reverse Voltage	V _{RSM}	V	1000	1300	1600	1800			
Average Forward Current	I _{F(AV)}	А	0.4 (Single-phase half sine wave 180° conduction) TL = 100°C, Lead length = 10mm)						
Surge(Non-Repetitive) Forward Current	I _{FSM}	А	30(Without PIV, 10ms conduction, Tj = 150°C start)						
I ² t Limit Value	l ² t	A ² s	3.6(Time = 2 ~ 10ms, I = RMS value)						
Operating Junction Temperature	Tj	°C	-65 ~ +150						
Storage Temperature	T _{stg}	°C	-65 ~ +200						

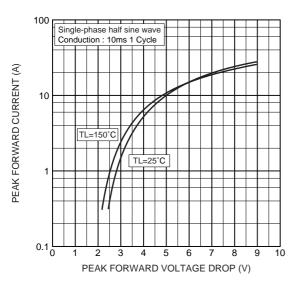
Notes (1) Lead mounting : Lead temperature 300°C max. to 3.2mm from body for 5sec. max.. (2) Mechanical strength : Bending 90°×2 cycles or 180°×1 cycle, Tensile 2kg, Twist 90°×1 cycle.

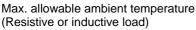
CHARACTERISTICS(T_L=25°C)

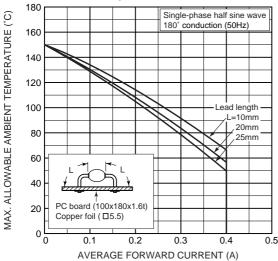
Items	Symbols	Units	Min.	Тур.	Max.	Test Conditions
Peak Reverse Current	I _{RRM}	μA	_	2.0	10	Rated V _{RRM}
Peak Forward Voltage	V _{FM}	V	-	_	2.5	I _{FM} =0.4 Ap, Single-phase half sine wave 1 cycle
Reverse Recovery Time	trr	μs	-	_	0.4	I _F =2mA, V _R =-15V
Steady State Thermal Impedance	R _{th(j-a)} R _{th(j-l)}	°C/W	_	_	80 50	Lead length = 10 mm

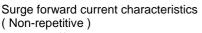
V11

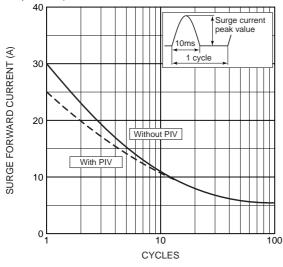
Forward characteristics



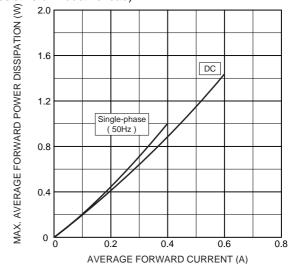




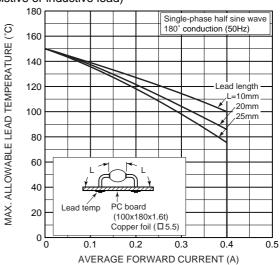




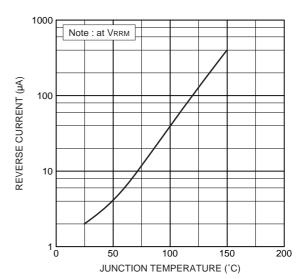
Max. average forward power dissipation (Resistive or inductive load)



Max. allowable lead temperature (Resistive or inductive load)

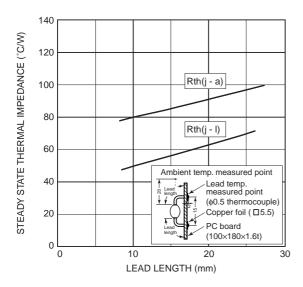


Typ. reverse current vs. junction temperature

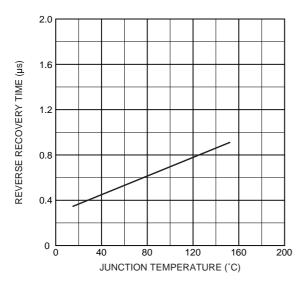


V11

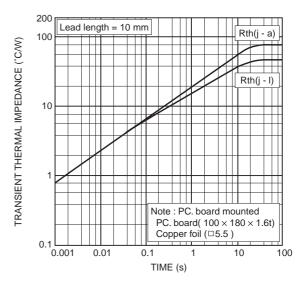
Steady state thermal impedance



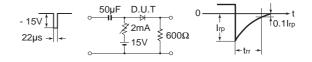
Typ. reverse recovery time vs. junction temperature



Transient thermal impedance



Reverse recovery time(trr) test circuit



HITACHI POWER SEMICONDUCTORS

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